



P.E.S. College of Engineering, Mandya - 571 401

(An Autonomous Institution affiliated to VTU, Belagavi)

First / Second Semester, B.E. - Semester End Examination; Sep. / Oct. - 2023

Basic Electronic Devices and Circuits

(Common to All Branches)

Time: 3 hrs

Max. Marks: 100

Course Outcomes

The Students will be able to:

CO1: Apply the knowledge of physics and mathematics to understand the principle of devices, number system, circuits and communication system.

CO2: Analyze the analog and digital circuits.

CO3: Design circuits for rectification, regulation, amplification and filtering.

CO4: Design the combination logic circuit.

Note: I) PART - A is compulsory. Two marks for each question.

II) PART - B: Answer any **Two** sub questions (from a, b, c) for a Maximum of **18 marks** from each unit.

Q. No.	Questions	Marks	BLs	COs	POs
I : PART - A		10			
1 a.	Mention the applications of Zener diodes.	2	L1	CO1	PO1
b.	Draw the structure of P-channel depletion type of MOSFET.	2	L1	CO1	PO1
c.	List the characteristics of OP-Amp.	2	L1	CO1	PO1
d.	Perform 1010X111 and write the resulting output.	2	L2	CO4	PO2
e.	Mention difference between FM and AM.	2	L1	CO5	PO2
II : PART - B		90			
UNIT - I		18			
2 a.	Define Q point. Explain load line analysis with relevant diagrams and equations.	9	L2	CO2	PO2
b.	Determine the output waveform for the network shown in Fig. 2(b) and obtain the output DC level and the required PIV of each diode.	9	L2	CO2	PO2
<p>Fig. 2(b)</p>					
c.	Explain Zener diode as voltage regulate for the following cases: i) V_i and R_L fixed ii) Fixed V_i and variable R_L	9	L2	CO2	PO2
UNIT - II		18			
3 a.	Explain basic construction and operation of n-channel enhancement type MOSFET with necessary diagrams and equations.	9	L2	CO1	PO1

- b. For the n-channel depletion-type MOSFET shown in Fig. 3(b), determine the following
 i) I_{DQ} and ii) V_{GSQ}

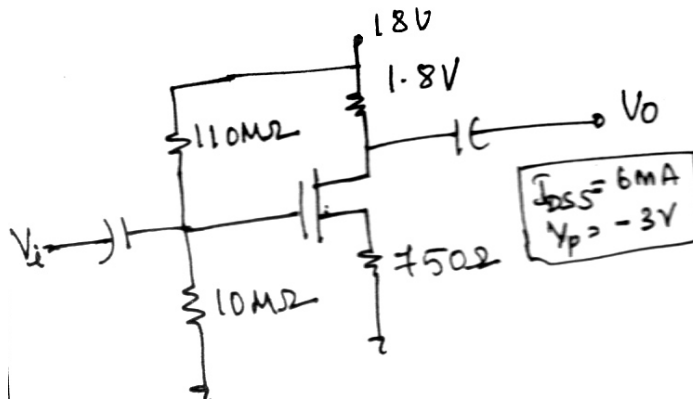


Fig. 3(b)

9 L3 CO2 PO2

- c. Explain the E-MOSFET voltage divider configuration with neat circuit diagram and AC equivalent configuration. Also determine the following for the same:
 i) Z_i and Z_o ii) G_m iii) A_v

9 L2 CO2 PO2

UNIT - III

18

- 4 a. Derive an expression for the voltage gain of an inverting Op-Amp with necessary diagram and equations.
 b. Explain the following with respect to Op-Amp with necessary circuit diagrams and equations.
 i) Current Controlled Voltage Source ii) Differentiator iii) 1st order High Pass Filter
 c. Show the connection of three Op-Amp stages using an LM348 IC to provide output that are 10, 20 and 50 times larger than the input use feedback resistor of $R_f = 500\text{ k}\Omega$ in all stages.

9 L2 CO3 PO2

9 L2 CO3 PO2

9 L2 CO3 PO2

UNIT - IV

18

- 5 a. Realize the following using only NAND;
 i) OR ii) AND iii) XOR
 b. Compute the following :
 i) $(54.325)_{10} = ()_2 = ()_8$
 ii) Perform $(1011)_2 - (0111)_2$ using 2's complement
 iii) Simplify and realize using basic gates $Y = \overline{BCD} + (\overline{B+C+D}) + \overline{BCDE}$
 c. Design and implement full adder using two half adders.

9 L2 CO4 PO2

9 L2 CO4 PO2

9 L2 CO4 PO2

UNIT - V

18

- 6 a. Explain Amplitude Modulation (AM) with the help of relevant sketch, waveforms and equations.
 b. List the characteristics of good receiver also explain super heterodyne receiver with neat block diagram.
 c. Explain the basic block diagram of Optical Fiber Communication (OFC) along with its applications.

9 L2 CO5 PO2

9 L2 CO5 PO2

9 L2 CO5 PO2